

DUAL OPERATIONAL AMPLIFIER

IL4580

GENERAL DESCRIPTION

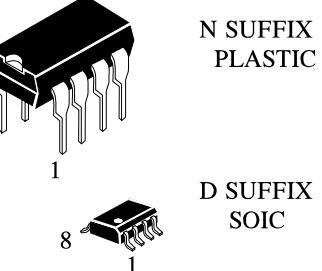
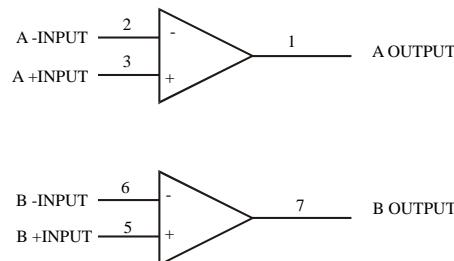
The IL4580 is the dual operational amplifier, specially designer for improving the tone control, which is most suitable for the audio application.

Featuring noiseless, higher gain bandwidth, high output current and low distortion ratio, and it is most suitable not only for acoustic electronic parts of audio pre-amp and active filter, but also for the industrial measurement tools. It is also suitable for the head phone amp at higher output current, and further more, it can be applied for the handy type set operational amplifier of general purpose in application of low voltage single supply type which is properly biased of the input low voltage source.

FEATURES

- Operating Voltage $(\pm 2 \text{ V} \sim \pm 18 \text{ V})$
- Wide Gain Bandwidth Product (15 MHz typ.)
- Slew Rate $(5 \text{ V}/\mu\text{s} \text{ typ.})$
- Bipolar Technology

BLOCK DIAGRAM



ORDERING INFORMATION

IL4580N Plastic

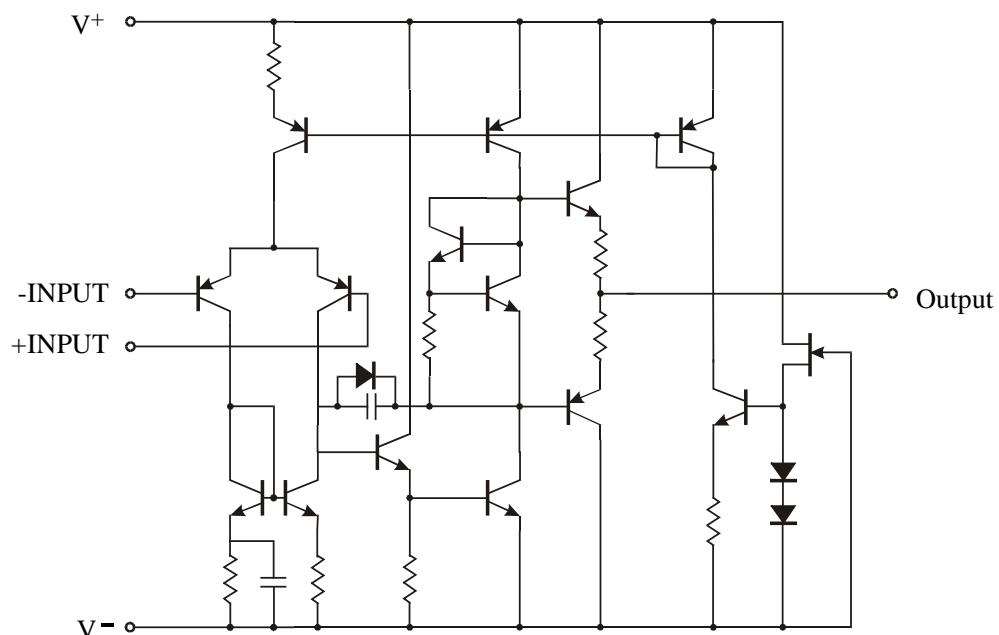
IL4580D SOIC

$T_A = -40^\circ \text{ to } 85^\circ \text{ C}$
for all packages.

PIN ASSIGNMENT

OUT 1	1 ●	8	V _{CC}
IN1(-)	2	7	OUT 2
IN1(+)	3	6	IN2(-)
GND	4	5	IN2(+)

EQUIVALENT CIRCUIT (1/2 Show)



ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

Symbol	Parameter	Ratings	Unit
V ⁺ /V ⁻	Supply Voltage	±18	V
V _{ID}	Differential Input Voltage	30	V
V _{IC}	Input Voltage	±15*	V
I _O	Output Current	±50	mA
Topr	Operation Temperature Range	-40 ~ +85	°C
Tstg	Storage Temperature Range	-60 ~ +125	°C

* For supply voltage less than ±15 V, the absolute maximum input voltage is equal to the supply voltage.

** Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device.

These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

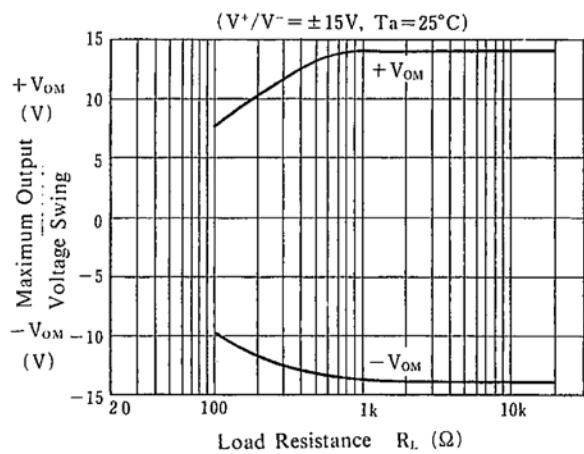
Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS (Ta=25°C, V⁺/V⁻ = ±15)

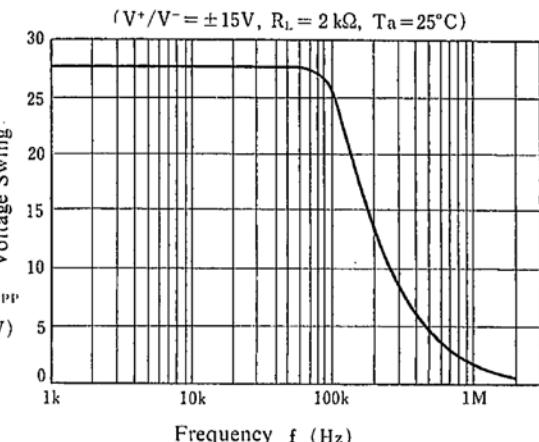
Symbol	Parameter	Test Condition	Min	Max	Unit
V _{IO}	Input Offset Voltage	R _S ≤ 10 kΩ	-	3	mV
I _{IO}	Input Offset Current		-	200	nA
I _B	Input Bias Current		-	500	nA
R _{IN}	Input Resistance		0.3	-	MΩ
A _V	Large Signal Voltage Gain	R _L ≥ 2 kΩ, V _O = ±10 V	90	-	dB
V _{OM}	Output Voltage Swing	R _L ≥ 2 kΩ	±12	-	V
V _{ICM}	Input Common Mode Voltage Range		±12	-	V
CMR	Common Mode Rejection Ratio	R _S ≤ 10 kΩ	80	-	dB
SVR	Supply Voltage Rejection Ratio	R _S ≤ 10 kΩ	80	-	dB
I _{CC}	Operating Current		-	9	mA
SR	Slew Rate	R _L ≥ 2 kΩ	4	6	V/μs

■ TYPICAL CHARACTERISTICS

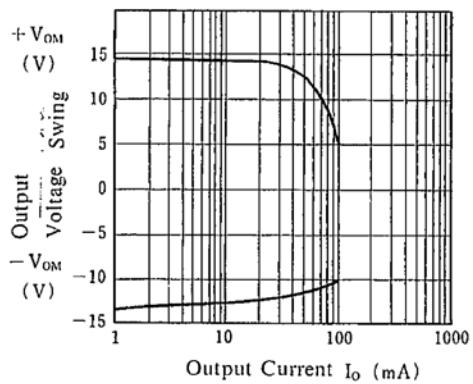
**Maximum Output Voltage Swing
vs. Load Resistance**



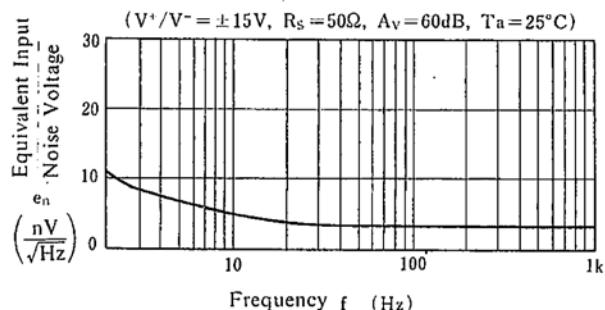
**Maximum Output Voltage Swing
vs. Frequency**



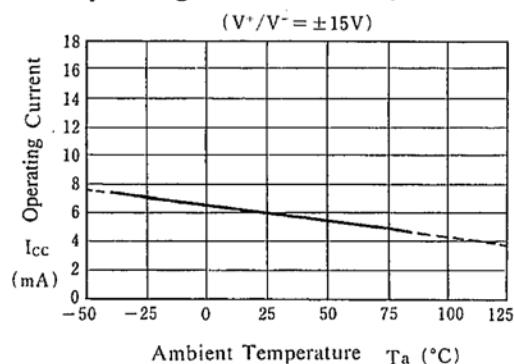
**Output Voltage Swing
vs. Output Current**



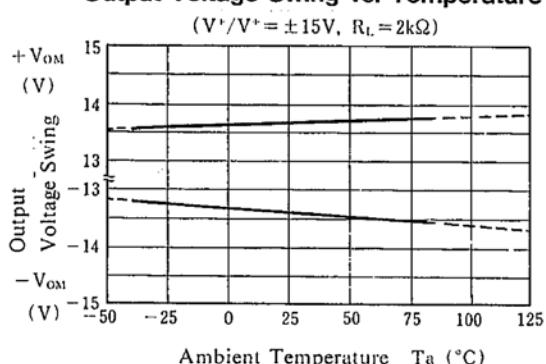
**Equivalent Input Noise Voltage
vs. Frequency**



Operating Current vs. Temperature

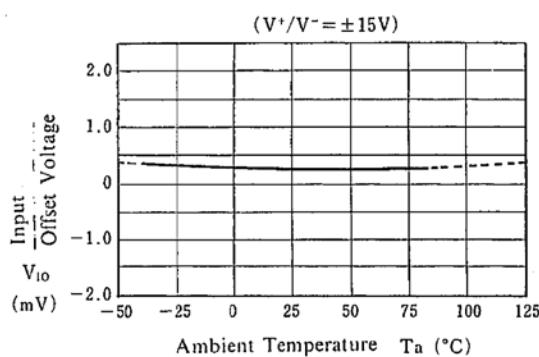


Output Voltage Swing vs. Temperature

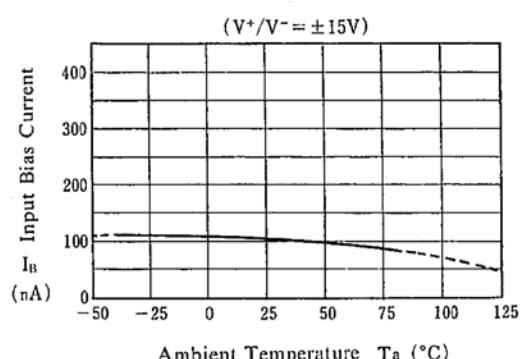


■ TYPICAL CHARACTERISTICS

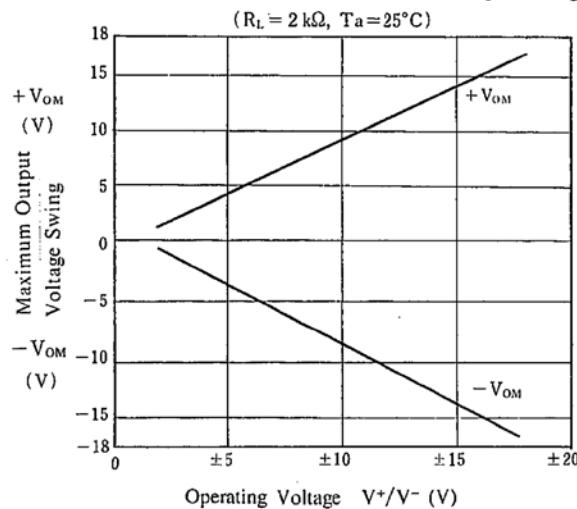
Input Offset Voltage vs. Temperature



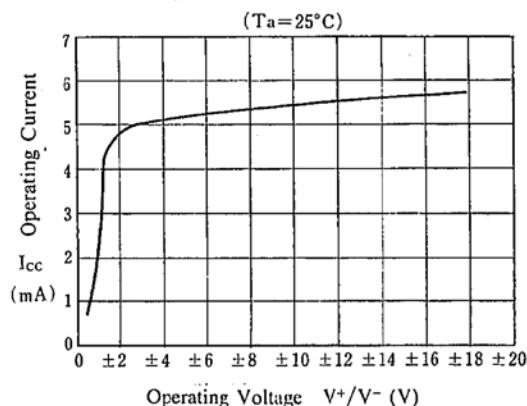
Input Bias Current vs. Temperature



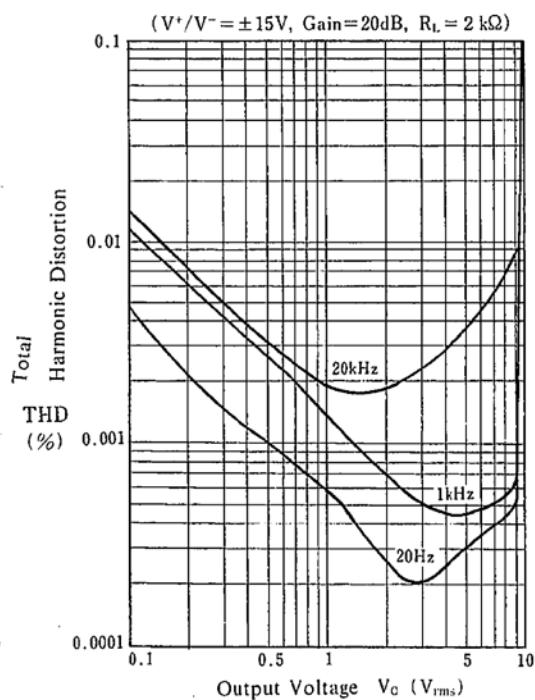
Maximum Output Voltage Swing vs. Operating Voltage



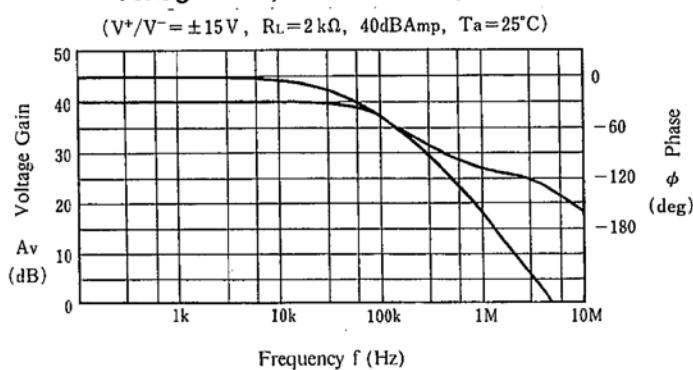
Operating Current vs. Operating Voltage

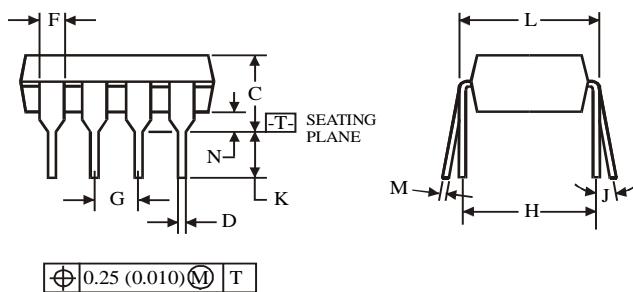
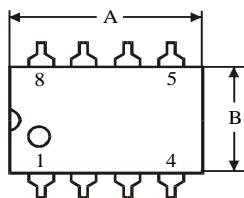


Total Harmonic Distortion vs. Output Voltage

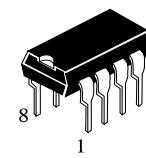


Voltage Gain, Phase vs. Frequency

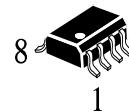
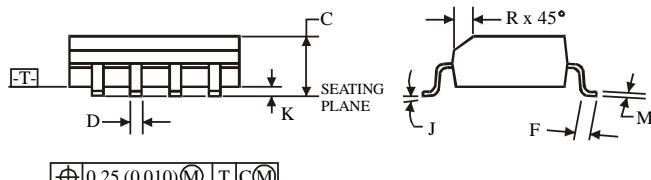
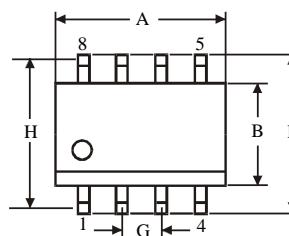


**N SUFFIX PLASTIC DIP
(MS - 001BA)**
**NOTES:**

- Dimensions "A", "B" do not include mold flash or protrusions.
- Maximum mold flash or protrusions 0.25 mm (0.010) per side.



Symbol	Dimension, mm	
	MIN	MAX
A	8.51	10.16
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G		2.54
H		7.62
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

**D SUFFIX SOIC
(MS - 012AA)**


Symbol	Dimension, mm	
	MIN	MAX
A	4.8	5
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G		1.27
H		5.72
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

NOTES:

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.

Данный компонент на территории Российской Федерации**Вы можете приобрести в компании MosChip.**

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибуторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ Р В 0015-002 и ЭС РД 009

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